

Low-Voltage CMOS Octal Transceiver

With 5 V-Tolerant Inputs and Outputs
(3-State, Non-Inverting)

MC74LCX245

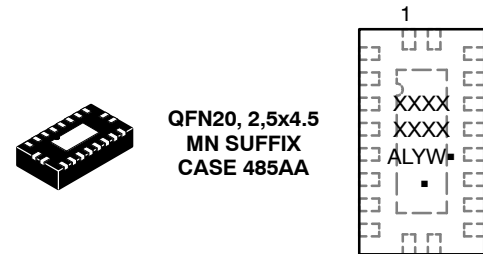
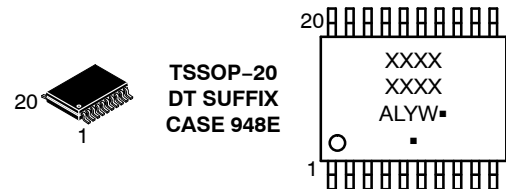
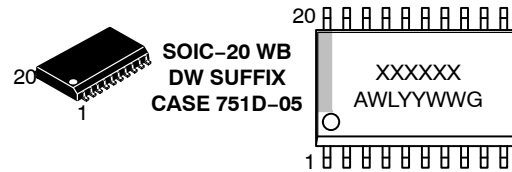
The MC74LCX245 is a high performance, non-inverting octal transceiver operating from a 1.65 to 5.5 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX245 inputs to be safely driven from 5 V devices if V_{CC} is less than 5.0 V. The MC74LCX245 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Current drive capability is 24 mA at both A and B ports at $V_{CC} = 3.0$ V. The Transmit/Receive (T/R) input determines the direction of data flow through the bi-directional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

Features

- Designed for 1.65 to 5.5 V V_{CC} Operation
- 5 V Tolerant – Interface Capability With 5 V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When $V_{CC} = 0$ V
- LVTTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability at $V_{CC} = 3.0$ V
- Near Zero Static Supply Current in All Three Logic States (10 μ A) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 100 mA
- ESD Performance: Human Body Model > 2000 V
- -Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MARKING DIAGRAMS



XXXXXXXX = Specific Device Code
A = Assembly Location
L, WL = Wafer Lot
Y, YY = Year
W, WW = Work Week
G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 7.

*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MC74LCX245

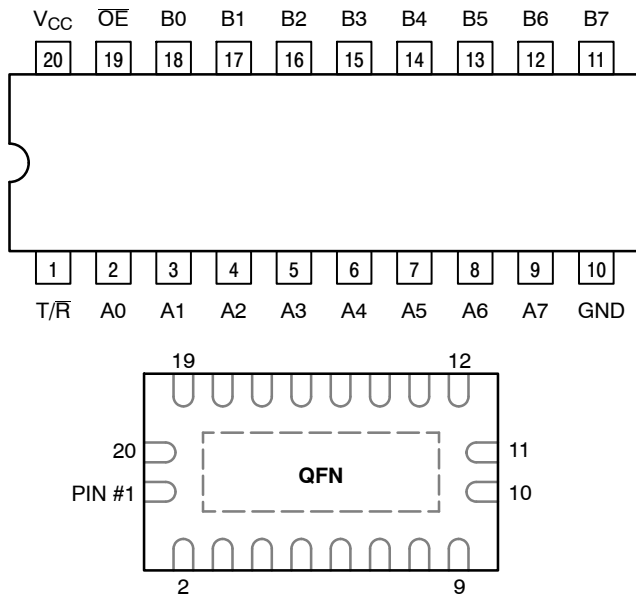


Figure 1. Pinout (Top View)

PIN NAMES

| PINS | FUNCTION |
|-----------------|--|
| \overline{OE} | Output Enable Input |
| T/R | Transmit/Receive Input |
| A0–A7 | Side A 3–State Inputs or 3–State Outputs |
| B0–B7 | Side B 3–State Inputs or 3–State Outputs |

TRUTH TABLE

| INPUTS | | OPERATING MODE Non-Inverting |
|-----------------|-----|---------------------------------|
| \overline{OE} | T/R | |
| L | L | B Data to A Bus |
| L | H | A Data to B Bus |
| H | X | Z |

H = High Voltage Level
 L = Low Voltage Level
 Z = High Impedance State
 X = High or Low Voltage Level and Transitions are Acceptable
 For I_{CC} reasons, Do Not Float Inputs

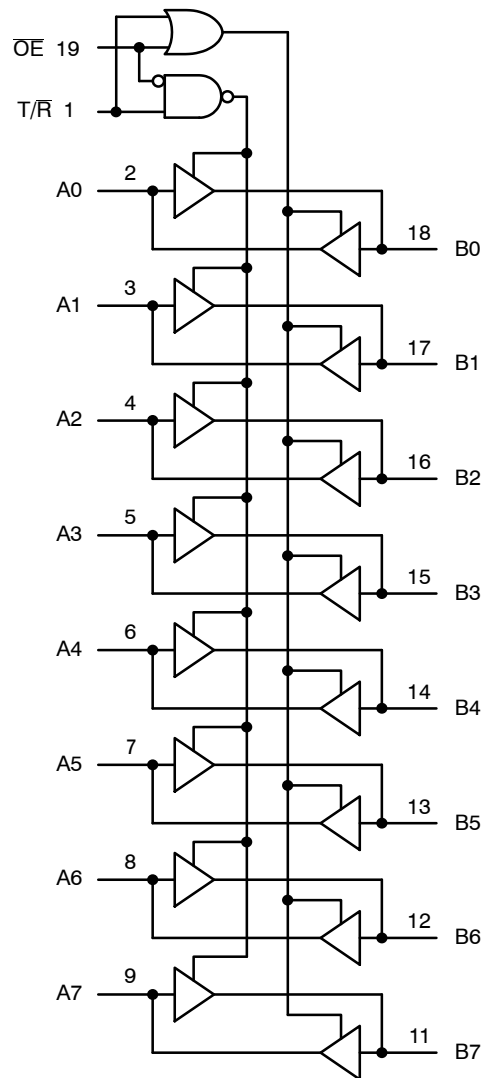


Figure 2. Logic Diagram

MC74LCX245

MAXIMUM RATINGS

| Symbol | Parameter | Condition | Value | Unit |
|-----------------------|--|-----------------------------------|------------------------|---------------|
| V_{CC} | DC Supply Voltage | | -0.5 to +6.5 | V |
| V_I | DC Input Voltage (Note 1) | | -0.5 to +6.5 | V |
| V_O | DC Output Voltage (Note 1) | Active-Mode (High or Low State) | -0.5 to $V_{CC} + 0.5$ | V |
| | | Tri-State Mode | -0.5 to +6.5 | |
| | | Power-Down Mode ($V_{CC} = 0$ V) | -0.5 to +6.5 | |
| I_{IK} | DC Input Diode Current | $V_{IN} < GND$ | -50 | mA |
| I_{OK} | DC Output Diode Current | $V_{OUT} < GND$ | -50 | mA |
| I_O | DC Output Source/Sink Current | | ± 50 | mA |
| I_{CC} or I_{GND} | DC Supply Current per Supply Pin or Ground Pin | | ± 100 | mA |
| T_{STG} | Storage Temperature Range | | -65 to +150 | $^{\circ}C$ |
| T_L | Lead Temperature, 1 mm from Case for 10 secs | | 260 | $^{\circ}C$ |
| T_J | Junction Temperature under Bias | | +150 | $^{\circ}C$ |
| θ_{JA} | Thermal Resistance (Note 2) | SOIC-20W | 96 | $^{\circ}C/W$ |
| | | WQFN20 | 99 | |
| | | QFN20 | 111 | |
| | | TSSOP-20 | 150 | |
| P_D | Power Dissipation in Still Air | SOIC-20W | 1302 | mW |
| | | WQFN20 | 1256 | |
| | | QFN20 | 1127 | |
| | | TSSOP-20 | 833 | |
| MSL | Moisture Sensitivity | SOIC-20W | Level 3 | - |
| | | All other packages | Level 1 | |
| F_R | Flammability Rating | Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in | - |
| V_{ESD} | ESD Withstand Voltage (Note 3) | Human Body Model | >2000 | V |
| | | Charged Device Model | N/A | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- I_O absolute maximum rating must be observed.
- Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
- HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD20-A115A (Machine Model) be discontinued.

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RECOMMENDED OPERATING CONDITIONS (Note 4)

| Symbol | Parameter | | Min | Typ | Max | Unit |
|---------------------------------|--------------------------------|--|------|----------|-----------------|------|
| V _{CC} | Supply Voltage | Operating | 1.65 | 2.5, 3.3 | 5.5 | V |
| | | Data Retention Only | 1.5 | 2.5, 3.3 | 5.5 | |
| V _I | Digital Input Voltage | | 0 | – | 5.5 | V |
| V _O | Output Voltage | Active-Mode (High or Low State) | 0 | – | V _{CC} | V |
| | | Tri-State Mode | 0 | – | 5.5 | |
| | | Power-Down Mode (V _{CC} = 0 V) | 0 | – | 5.5 | |
| T _A | Operating Free-Air Temperature | | –55 | | +125 | °C |
| t _r , t _f | Input Rise or Fall Rate | V _{CC} = 1.65 V to 1.95 V | 0 | – | 20 | ns/V |
| | | V _{CC} = 2.3 V to 2.7 V | 0 | – | 20 | |
| | | V _{IN} from 0.8 V to 2.0 V, V _{CC} = 3.0 V | 0 | – | 10 | |
| | | V _{CC} = 4.5 V to 5.5 V | 0 | – | 5 | |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Conditions | V _{CC} (V) | T _A = –40°C to +85°C | | T _A = –55°C to +125°C | | Unit |
|------------------|--------------------------------|--|---------------------|---------------------------------|------------------------|----------------------------------|------------------------|------|
| | | | | Min | Max | Min | Max | |
| V _{IH} | High-Level Input Voltage | | 1.65 to 1.95 | 0.65 × V _{CC} | | 0.65 × V _{CC} | | V |
| | | | 2.3 to 2.7 | 1.7 | | 1.7 | | |
| | | | 2.7 to 3.6 | 2.0 | | 2.0 | | |
| | | | 4.5 to 5.5 | 0.7 × V _{CC} | | 0.7 × V _{CC} | | |
| V _{IL} | Low-Level Input Voltage | | 1.65 to 1.95 | | 0.35 × V _{CC} | | 0.35 × V _{CC} | V |
| | | | 2.3 to 2.7 | | 0.7 | | 0.7 | |
| | | | 2.7 to 3.6 | | 0.8 | | 0.8 | |
| | | | 4.5 to 5.5 | | 0.3 × V _{CC} | | 0.3 × V _{CC} | |
| V _{OH} | High-Level Output Voltage | V _I = V _{IH} or V _{IL} | 1.65 to 5.5 | V _{CC} – 0.1 | – | V _{CC} – 0.1 | – | V |
| | | I _{OH} = –100 μA | 1.65 | 1.2 | – | 1.2 | – | |
| | | I _{OH} = –4 mA | 2.3 | 1.8 | – | 1.8 | – | |
| | | I _{OH} = –8 mA | 2.7 | 2.2 | – | 2.2 | – | |
| | | I _{OH} = –12 mA | 3.0 | 2.4 | – | 2.4 | – | |
| | | I _{OH} = –16 mA | 3.0 | 2.2 | – | 2.2 | – | |
| | | I _{OH} = –24 mA | 4.5 | 3.8 | – | 3.8 | – | |
| V _{OL} | Low-Level Output Voltage | V _I = V _{IH} or V _{IL} | 1.65 to 5.5 | – | 0.1 | – | 0.1 | V |
| | | I _{OL} = 100 μA | 1.65 | – | 0.45 | – | 0.45 | |
| | | I _{OL} = 4 mA | 2.3 | – | 0.6 | – | 0.6 | |
| | | I _{OL} = 8 mA | 2.7 | – | 0.4 | – | 0.4 | |
| | | I _{OL} = 12 mA | 3.0 | – | 0.4 | – | 0.4 | |
| | | I _{OL} = 16 mA | 3.0 | – | 0.55 | – | 0.55 | |
| | | I _{OL} = 24 mA | 4.5 | – | 0.6 | – | 0.6 | |
| I _I | Input Leakage Current | V _I = 0 to 5.5 V | 3.6 | – | ±5.0 | – | ±5.0 | μA |
| I _{OZ} | 3-State Output Leakage Current | V _I = V _{IH} or V _{IL} , V _O = 0 V to 5.5 V | 3.6 | – | ±5.0 | – | ±5.0 | μA |
| I _{OFF} | Power Off Leakage Current | V _I = 5.5 V or V _O = 5.5 V | 0 | – | 10 | – | 10 | μA |

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DC ELECTRICAL CHARACTERISTICS (continued)

| Symbol | Parameter | Conditions | V _{CC} (V) | T _A = -40°C to +85°C | | T _A = -55°C to +125°C | | Unit |
|------------------|---------------------------------------|---|---------------------|---------------------------------|-----|----------------------------------|-----|------|
| | | | | Min | Max | Min | Max | |
| I _{CC} | Quiescent Supply Current | V _I = 5.5 V or GND | 3.6 | - | 10 | - | 10 | μA |
| ΔI _{CC} | Increase in I _{CC} per Input | V _{IH} = V _{CC} - 0.6 V | 2.3 to 3.6 | - | 500 | - | 500 | μA |

AC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | V _{CC} (V) | T _A = -40°C to +85°C | | T _A = -55°C to +125°C | | Unit |
|---------------------------------------|--------------------------------|---------------------|---------------------|---------------------------------|------|----------------------------------|------|------|
| | | | | Min | Max | Min | Max | |
| t _{PLH} , t _{PHL} | Propagation Delay, D to O | See Figures 3 and 4 | 1.65 to 1.95 | - | 10.3 | - | 10.3 | ns |
| | | | 2.3 to 2.7 | - | 8.4 | - | 8.4 | |
| | | | 2.7 | - | 8.0 | - | 8.0 | |
| | | | 3.0 to 3.6 | - | 7.0 | - | 7.0 | |
| | | | 4.5 to 5.5 | - | 5.0 | - | 5.0 | |
| t _{PZH} , t _{PZL} | Output Enable Time, OE to O | See Figures 3 and 4 | 1.65 to 1.95 | - | 13.0 | - | 13.0 | ns |
| | | | 2.3 to 2.7 | - | 10.5 | - | 10.5 | |
| | | | 2.7 | - | 9.5 | - | 9.5 | |
| | | | 3.0 to 3.6 | - | 8.5 | - | 8.5 | |
| | | | 4.5 to 5.5 | - | 7.0 | - | 7.0 | |
| t _{PHZ} , t _{PLZ} | Output Disable Time, OE to O | See Figures 3 and 4 | 1.65 to 1.95 | - | 11.0 | - | 11.0 | ns |
| | | | 2.3 to 2.7 | - | 9.0 | - | 9.0 | |
| | | | 2.7 | - | 8.5 | - | 8.5 | |
| | | | 3.0 to 3.6 | - | 7.5 | - | 7.5 | |
| | | | 4.5 to 5.5 | - | 6.0 | - | 6.0 | |
| t _{OSSL} , t _{OSLH} | Output to Output Skew (Note 5) | | 1.65 to 1.95 | - | - | - | - | ns |
| | | | 2.3 to 2.7 | - | 1.0 | - | 1.0 | |
| | | | 2.7 | - | 1.0 | - | 1.0 | |
| | | | 3.0 to 3.6 | - | 1.0 | - | 1.0 | |
| | | | 5.0 | - | 1.0 | - | 1.0 | |

5. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSSL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

MC74LCX245

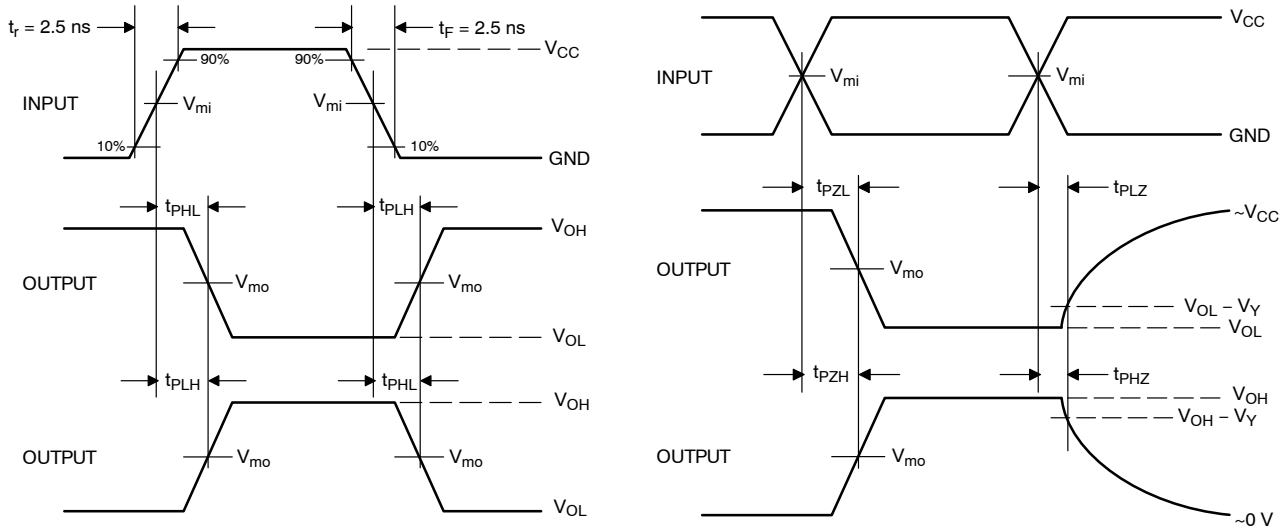
DYNAMIC SWITCHING CHARACTERISTICS

| Symbol | Characteristic | Condition | T _A = +25°C | | | Unit |
|------------------|-------------------------------------|--|------------------------|--------------|-----|--------|
| | | | Min | Typ | Max | |
| V _{OLP} | Dynamic LOW Peak Voltage (Note 6) | V _{CC} = 3.3 V, C _L = 50 pF, V _{IH} = 3.3 V, V _{IL} = 0 V V _{CC} = 2.5 V, C _L = 30 pF, V _{IH} = 2.5 V, V _{IL} = 0 V | | 0.8 0.6 | | V V |
| V _{OLV} | Dynamic LOW Valley Voltage (Note 6) | V _{CC} = 3.3 V, C _L = 50 pF, V _{IH} = 3.3 V, V _{IL} = 0 V V _{CC} = 2.5 V, C _L = 30 pF, V _{IH} = 2.5 V, V _{IL} = 0 V | | -0.8 -0.6 | | V V |

6. Number of outputs defined as “n”. Measured with “n-1” outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

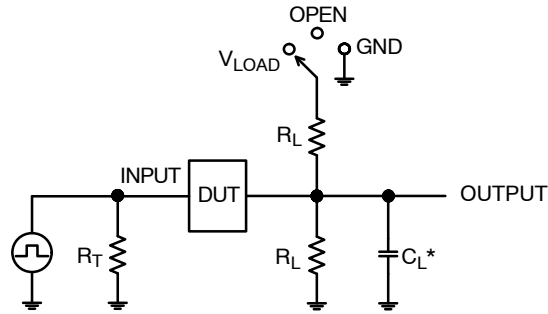
| Symbol | Parameter | Condition | Typical | Unit |
|------------------|-------------------------------|--|---------|------|
| C _{IN} | Input Capacitance | V _{CC} = 3.3 V, V _I = 0 V or V _{CC} | 7 | pF |
| C _{I/O} | Input/Output Capacitance | V _{CC} = 3.3 V, V _I = 0 V or V _{CC} | 8 | pF |
| C _{PD} | Power Dissipation Capacitance | 10 MHz, V _{CC} = 3.3 V, V _I = 0 V or V _{CC} | 25 | pF |



| V _{CC} , V | R _L , Ω | C _L , pF | V _{LOAD} | V _{mi} , V | V _{mo} , V | V _Y , V |
|---------------------|--------------------|---------------------|---------------------|---------------------|---------------------|--------------------|
| 1.65 to 1.95 | 500 | 30 | 2 × V _{CC} | V _{CC} /2 | V _{CC} /2 | 0.15 |
| 2.3 to 2.7 | 500 | 30 | 2 × V _{CC} | V _{CC} /2 | V _{CC} /2 | 0.15 |
| 2.7 | 500 | 50 | 6 V | 1.5 | V _{CC} /2 | 0.3 |
| 3.0 to 3.6 | 500 | 50 | 6 V | 1.5 | V _{CC} /2 | 0.3 |
| 4.5 to 4.5 | 500 | 50 | 2 × V _{CC} | V _{CC} /2 | V _{CC} /2 | 0.3 |

Figure 3. Switching Waveforms

MC74LCX245



C_L includes probe and jig capacitance
 R_T is Z_{OUT} of pulse generator (typically 50 Ω)
 $f = 1$ MHz

| Test | Switch Position |
|---------------------|-----------------|
| t_{PLH} / t_{PHL} | Open |
| t_{PLZ} / t_{PZL} | V_{LOAD} |
| t_{PHZ} / t_{PZH} | GND |

Figure 4. Test Circuit

ORDERING INFORMATION

| Device | Marking | Package | Shipping [†] |
|--------------------|------------|----------------|--|
| MC74LCX245DWG | LCX245 | SOIC-20 WB | 38 Units / Rail |
| MC74LCX245DWR2G | LCX245 | SOIC-20 WB | 1000 / Tape & Reel |
| MC74LCX245DTG | LCX 245 | TSSOP-20 | 75 Units / Rail |
| MC74LCX245DTR2G | LCX 245 | TSSOP-20 | 2500 / Tape & Reel |
| MC74LCX245DTR2G-Q* | LCX 245 | TSSOP-20 | 2500 / Tape & Reel |
| MC74LCX245MNTWG | LCX 245 | QFN20, 2.5x4.5 | 3000 / Tape & Reel (4mm pitch carrier tape) |

DISCONTINUED (Note 7)

| | | | |
|-------------------|------------|-----------------------|------------------|
| NLV74LCX245DTR2G* | LCX 245 | TSSOP-20 (Pb-Free) | 2500 Tape & Reel |
|-------------------|------------|-----------------------|------------------|

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

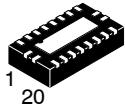
*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

7. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

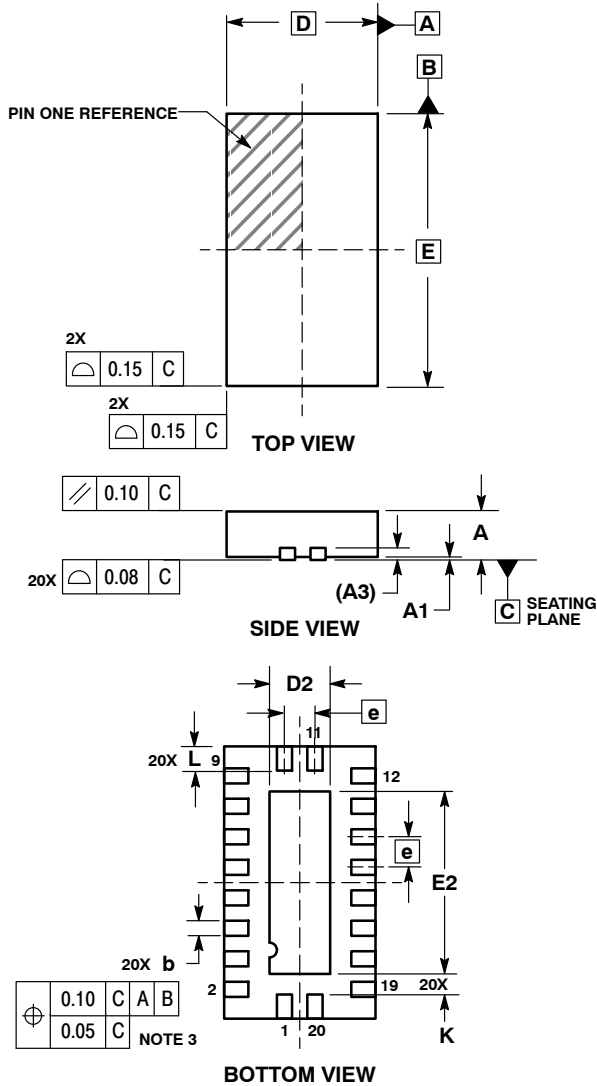
ON Semiconductor®



SCALE 2:1

QFN20, 2.5x4.5 MM
CASE 485AA-01
ISSUE B

DATE 30 APR 2010

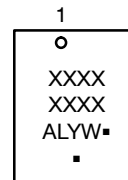


NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSIONS b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
- COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

| DIM | MILLIMETERS | |
|-----|-------------|------|
| | MIN | MAX |
| A | 0.80 | 1.00 |
| A1 | 0.00 | 0.05 |
| A3 | 0.20 REF | |
| b | 0.20 | 0.30 |
| D | 2.50 BSC | |
| D2 | 0.85 | 1.15 |
| E | 4.50 BSC | |
| E2 | 2.85 | 3.15 |
| e | 0.50 BSC | |
| K | 0.20 | --- |
| L | 0.35 | 0.45 |

GENERIC MARKING DIAGRAM*



- XXXX = Specific Device Code
- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

| | | |
|-------------------------|--------------------------|--|
| DOCUMENT NUMBER: | 98AON12653D | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| DESCRIPTION: | QFN20. 2.5X4.5 MM | PAGE 1 OF 1 |

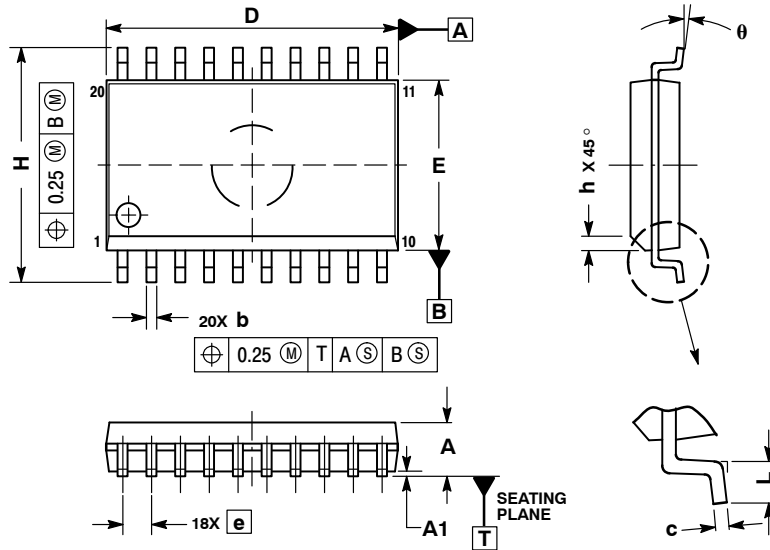
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SCALE 1:1

SOIC-20 WB
CASE 751D-05
ISSUE H

DATE 22 APR 2015

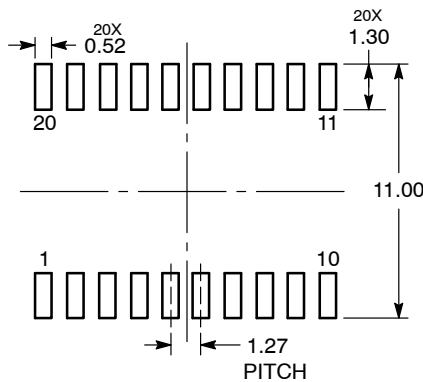


NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

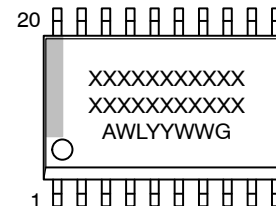
| DIM | MILLIMETERS | |
|-----|-------------|-------|
| | MIN | MAX |
| A | 2.35 | 2.65 |
| A1 | 0.10 | 0.25 |
| b | 0.35 | 0.49 |
| c | 0.23 | 0.32 |
| D | 12.65 | 12.95 |
| E | 7.40 | 7.60 |
| e | 1.27 BSC | |
| H | 10.05 | 10.55 |
| h | 0.25 | 0.75 |
| L | 0.50 | 0.90 |
| θ | 0° | 7° |

RECOMMENDED
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*

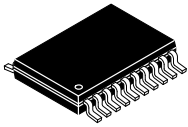


- XXXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

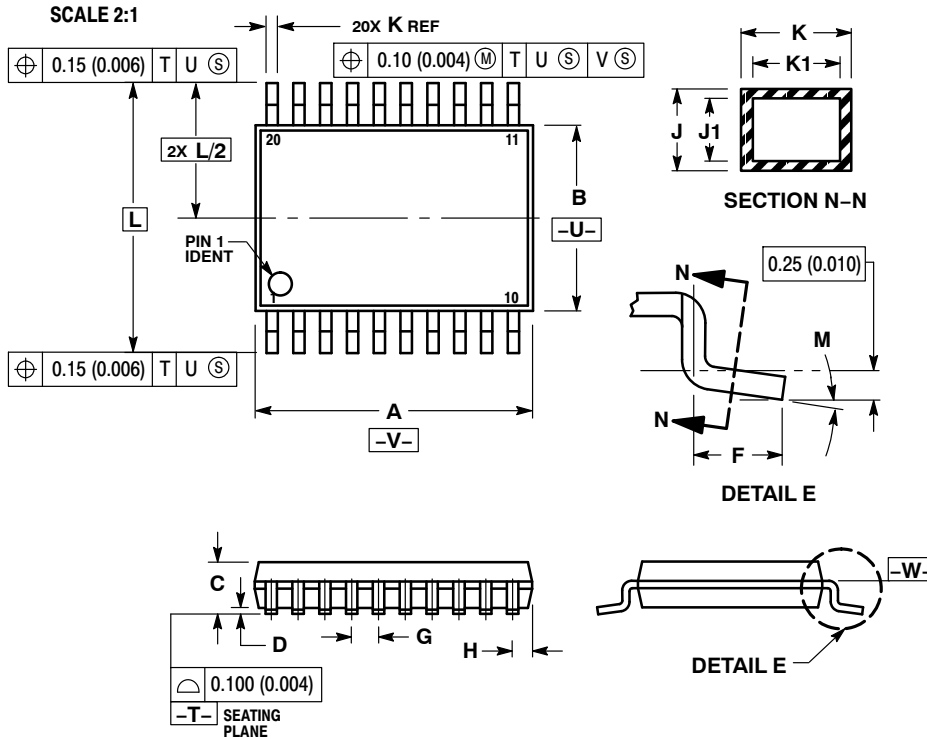
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TSSOP-20 WB
CASE 948E
ISSUE D

DATE 17 FEB 2016

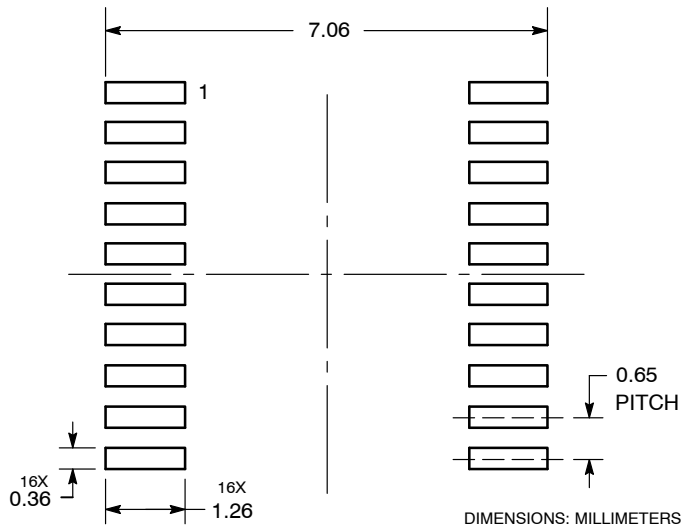


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

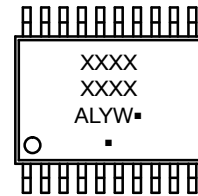
| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 6.40 | 6.60 | 0.252 | 0.260 |
| B | 4.30 | 4.50 | 0.169 | 0.177 |
| C | --- | 1.20 | --- | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 BSC | | 0.026 BSC | |
| H | 0.27 | 0.37 | 0.011 | 0.015 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 BSC | | 0.252 BSC | |
| M | 0° | 8° | 0° | 8° |

RECOMMENDED
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*



- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

| | | |
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